

# **isc Silicon NPN Power Transistor**

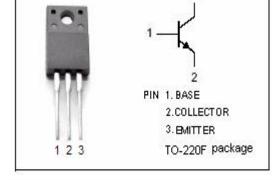
# **BU1507AX**

### **DESCRIPTION**

- · Collector-Emitter Sustaining Voltage-
  - : V<sub>CEO(SUS)</sub>= 700V(Min.)
- · High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **APPLICATIONS**

 Designed for use in horizontal deflection circuits of color TV receivers and computer monitors.

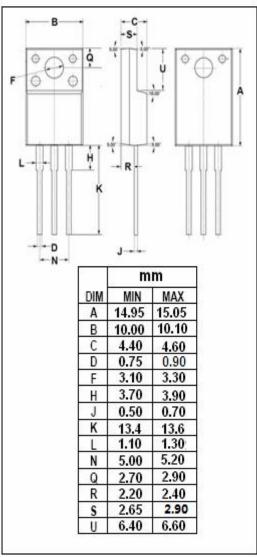


## ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CESM</sub>	Collector-Emitter Voltage V <sub>BE</sub> = 0	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	700	V
V <sub>EBO</sub>	Emitter-Base Voltage	7.5	V
Ic	Collector Current-Continuous	8	А
I <sub>CM</sub>	Collector Current-Peak	15	А
lΒ	Base Current-Continuous	4	Α
I <sub>BM</sub>	Base Current-peak	6	А
Pc	Junction Temperature 150		W
T <sub>j</sub>			$^{\circ}$ C
T <sub>stg</sub>			$^{\circ}$ C

#### THERMAL CHARACTERISTICS

	SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	3.7	°C/W





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**BU1507AX** 

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	700			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA; I <sub>C</sub> = 0	7.5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A			5.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A			1.1	V
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CE</sub> = V <sub>CESM</sub> ; V <sub>BE</sub> = 0 V <sub>CE</sub> = V <sub>CESM</sub> ; V <sub>BE</sub> = 0; T <sub>C</sub> =125°C			1.0 2.0	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7.5V; I <sub>C</sub> = 0			1.0	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 100mA; V <sub>CE</sub> = 5V		17		
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 4A; V <sub>CE</sub> = 5V	5		9	
Сов	Collector Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		68		pF

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